

**2SA1037**  
**PNP TRANSISTOR**

**FEATURES**

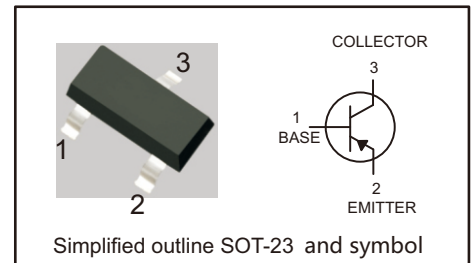
- Excellent hFE linearity
- Complements the 2SC2412Q/R/S

**CLASSIFICATION OF hFE**

Rank	Q	R	S
Range	120-270	180-390	270-560

**PINNING**

PIN	DESCRIPTION
1	BASE
2	EMITTER
3	COLLECTOR



**MAXIMUM RATINGS (Ta =25°C unless otherwise noted)**

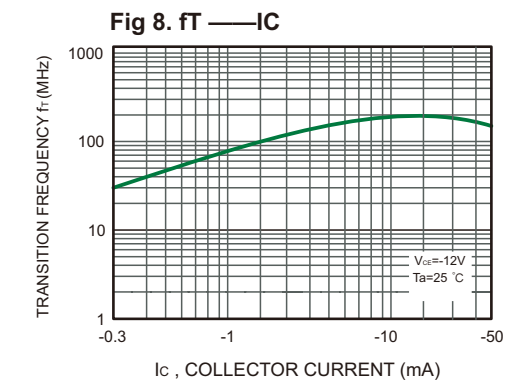
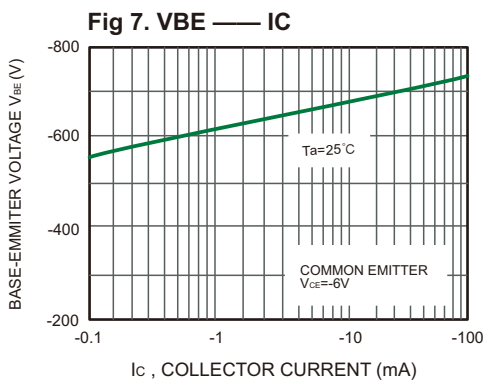
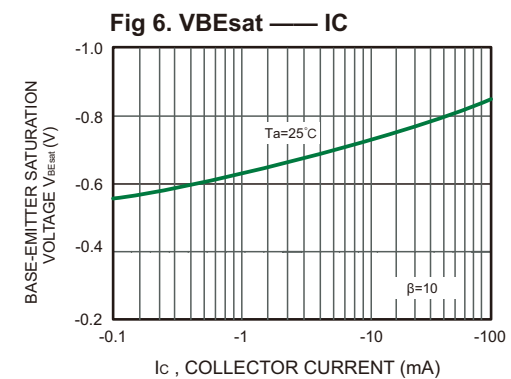
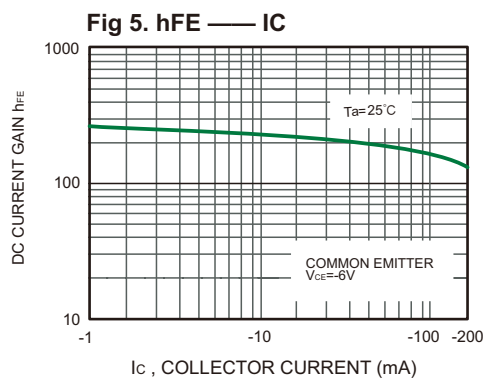
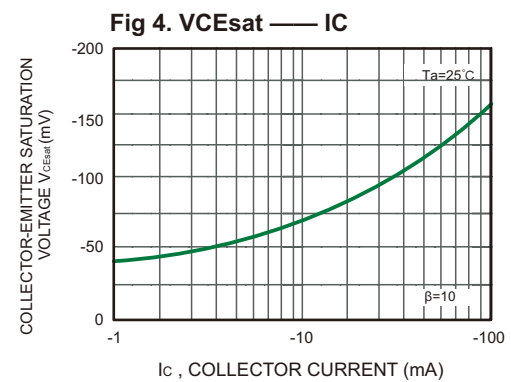
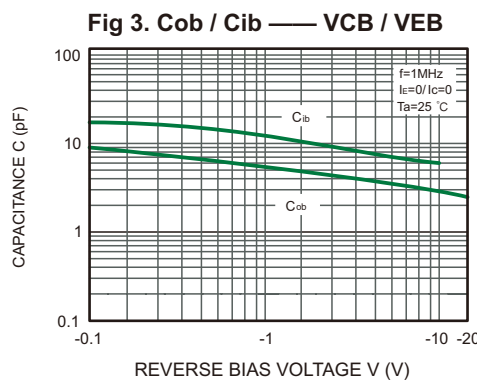
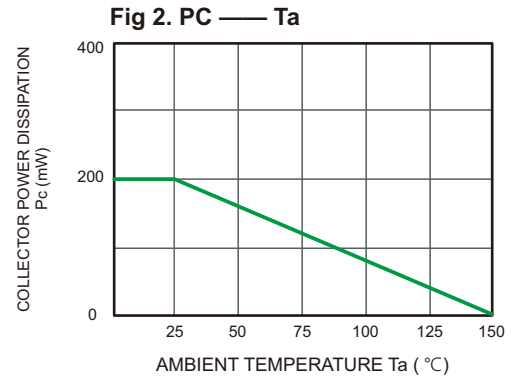
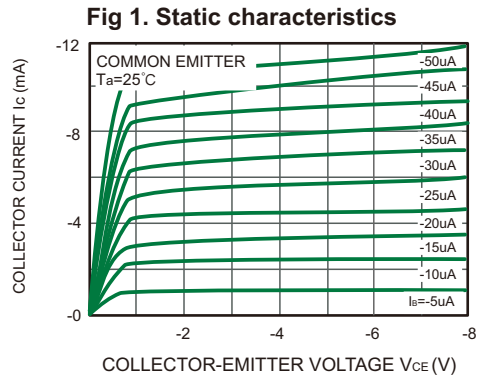
Parameter	Symbol	Value	Unit
Collector–Base Voltage	$V_{CBO}$	-60	V
Collector–Emitter Voltage	$V_{CEO}$	-50	V
Emitter–Base Voltage	$V_{EBO}$	-6	V
Collector Current — Continuous	$I_C$	-150	mA
Collector Power Dissipation	$P_C$	200	mW
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	417	°C/W
Operation Junction and Storage Temperature Range	$T_J, T_{stg}$	-55~ +150	°C

**ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted.)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -50\mu A, I_E = 0$	-60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -1mA, I_B = 0$	-50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -50\mu A, I_C = 0$	-6			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -60V, I_E = 0$			-100	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -6V, I_C = 0$			-100	nA
DC current gain	$h_{FE}$	$V_{CE} = -6V, I_C = -1mA$	120		560	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -50mA, I_B = -5mA$			-0.5	V
Transition frequency	$f_T$	$V_{CE} = -12V, I_C = -2mA, f=30MHz$		140		MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -12V, I_E = 0, f = 1MHz$			5	pF

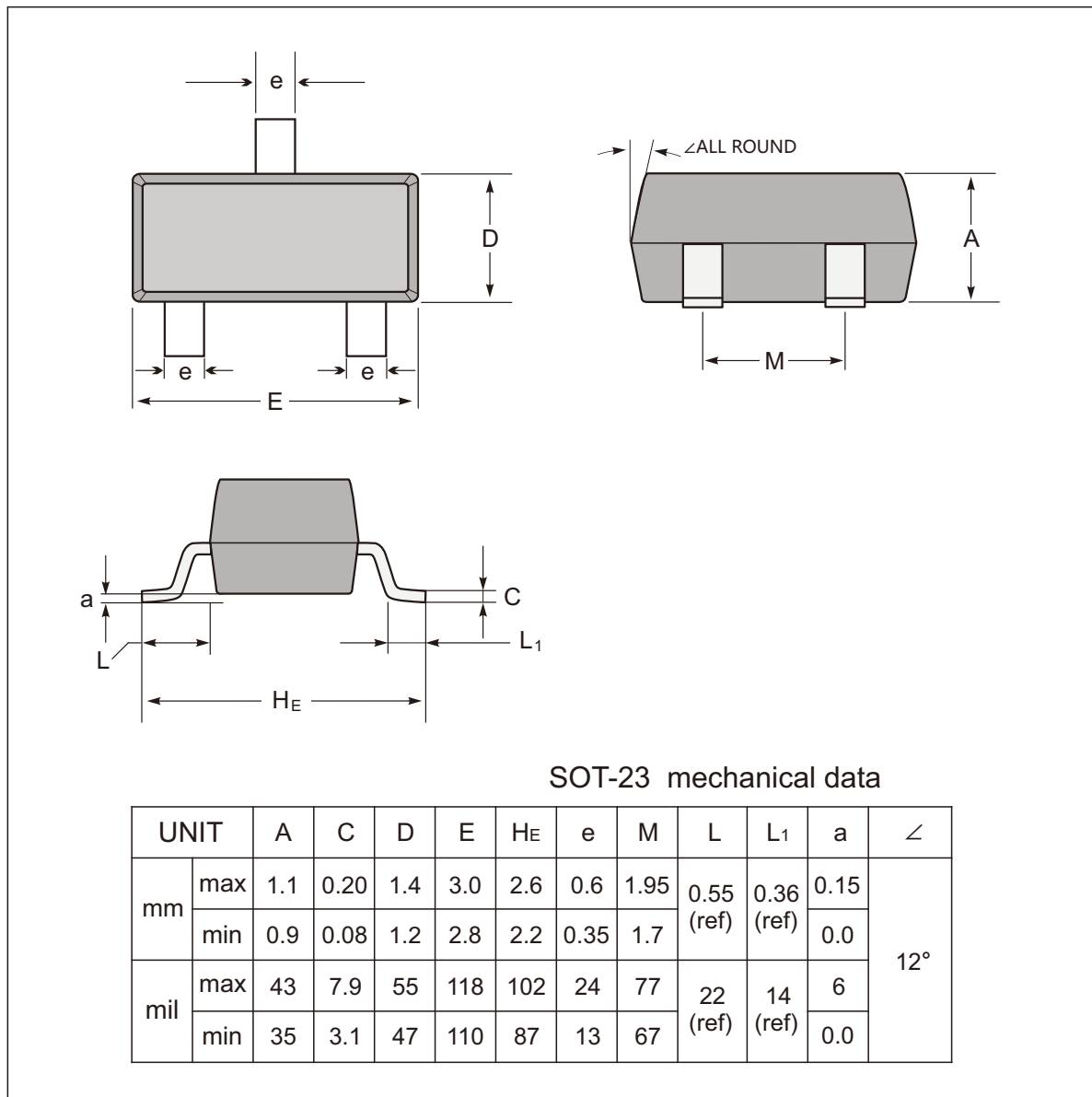


TYPICAL CHARACTERISTICS

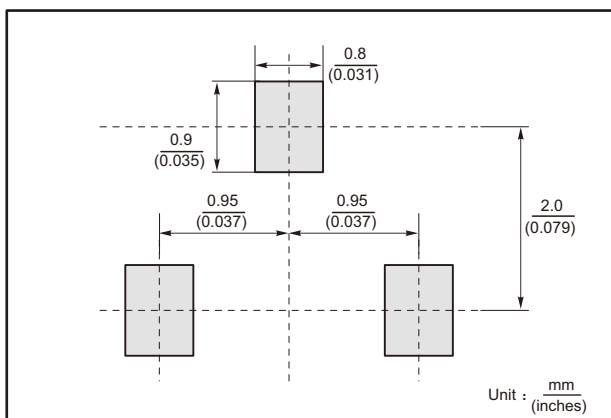




### SOT-23 Package Outline Dimensions



#### The recommended mounting pad size



#### Marking

Type number	Marking code
2SA1037Q	FQ
2SA1037R	FR
2SA1037S	FS



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